

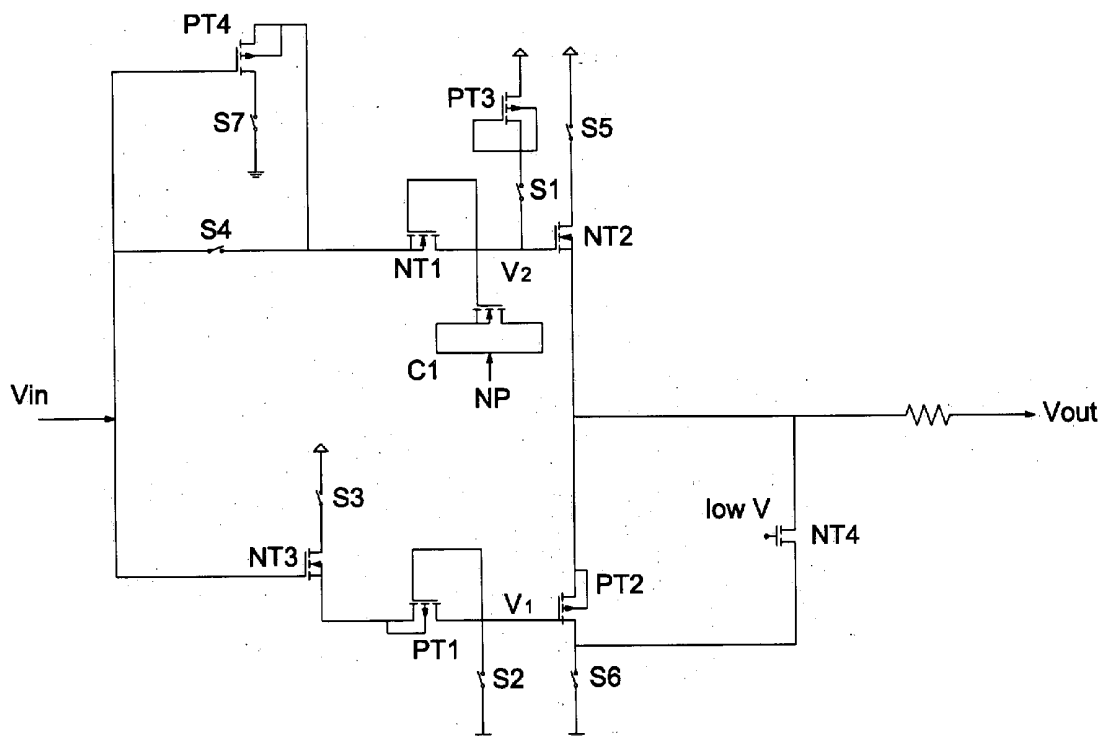


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(19) **United States**(12) **Patent Application Publication**
Chiu(10) **Pub. No.: US 2004/0263464 A1**(43) **Pub. Date: Dec. 30, 2004**(54) **LOW POWER SOURCE DRIVER FOR
LIQUID CRYSTAL DISPLAY**(52) **U.S. Cl. 345/100**(76) **Inventor: Ming Cheng Chiu, Shanhsua Town
(TW)**(57) **ABSTRACT**

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Disclosed is a source driver for receiving an input voltage and generating an output voltage to drive a data line in a liquid crystal display apparatus. In the source driver, first and second P-channel MOS transistors are together used as a primary source follower to trace the input voltage thereby eliminating the body effect and keeping the loading charge loss constant. First and second N-channel MOS transistors are used, as a secondary source follower. A capacitor is used for boosting the voltage of the drain of the first N-channel MOS transistor on the level of at least the input voltage plus the threshold voltage of the N-channel MOS transistor. In addition, an extra switch is used to reach the accurate output voltage when the output voltage is approaching the input voltage.

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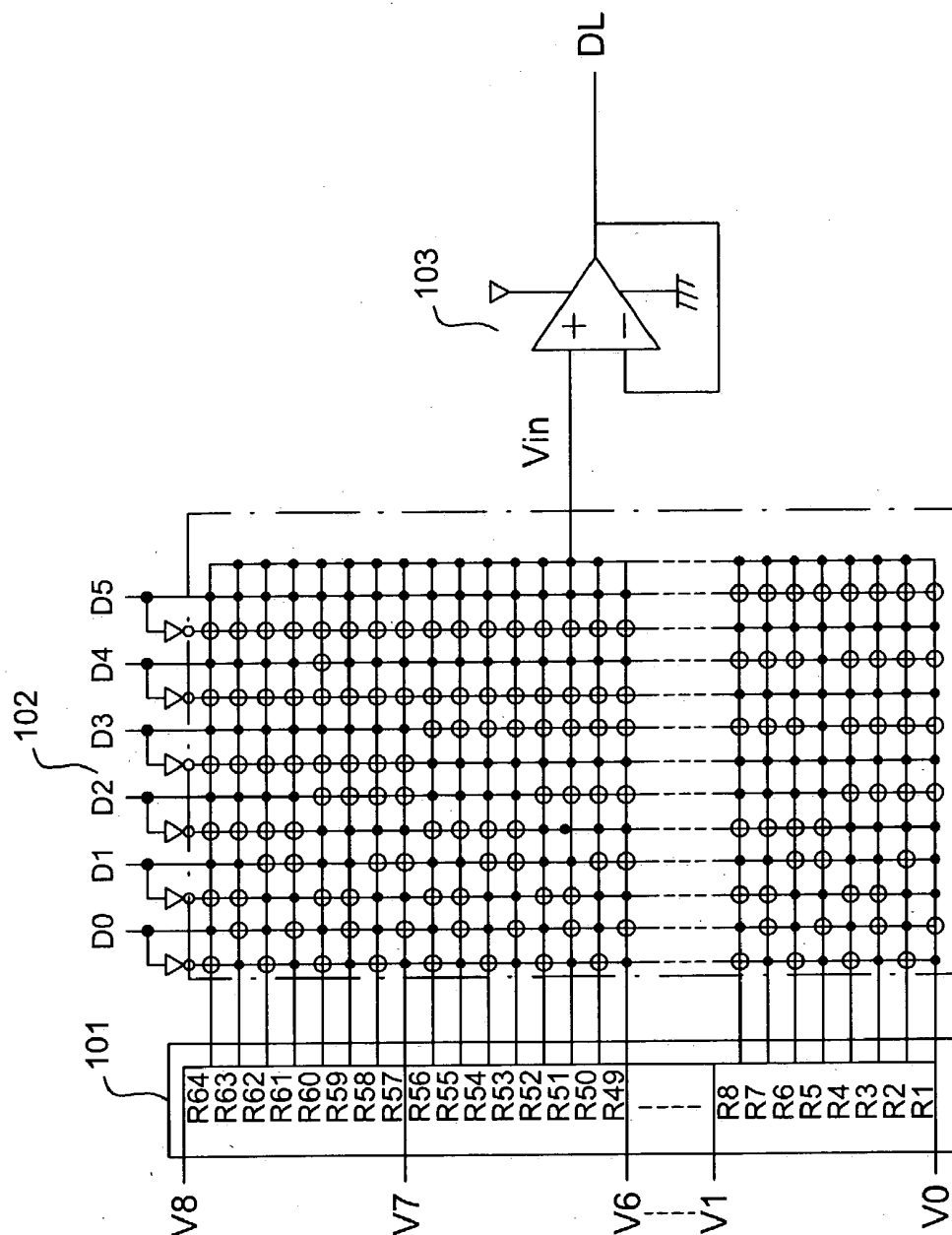
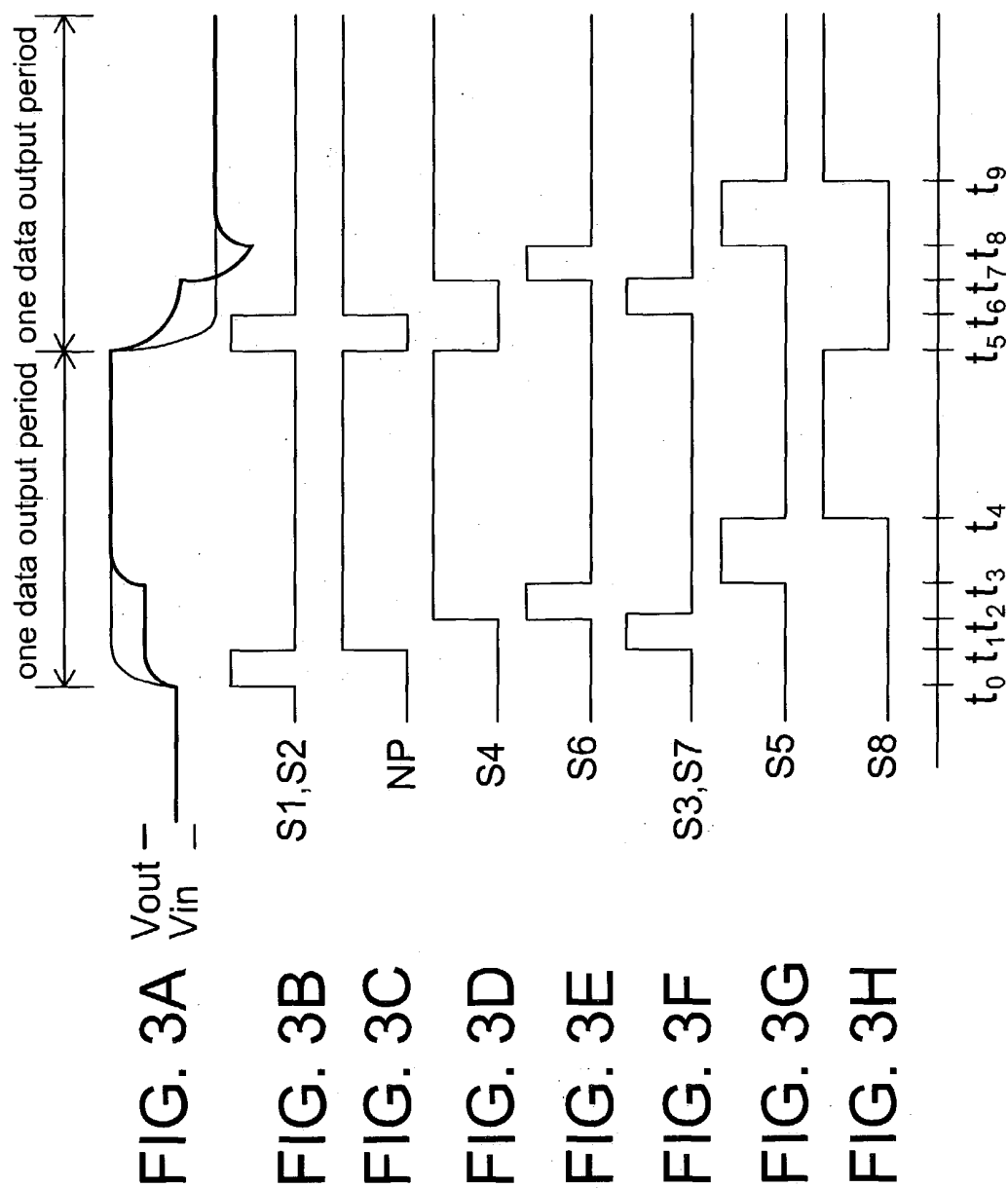


FIG. 1 (PRIOR ART)



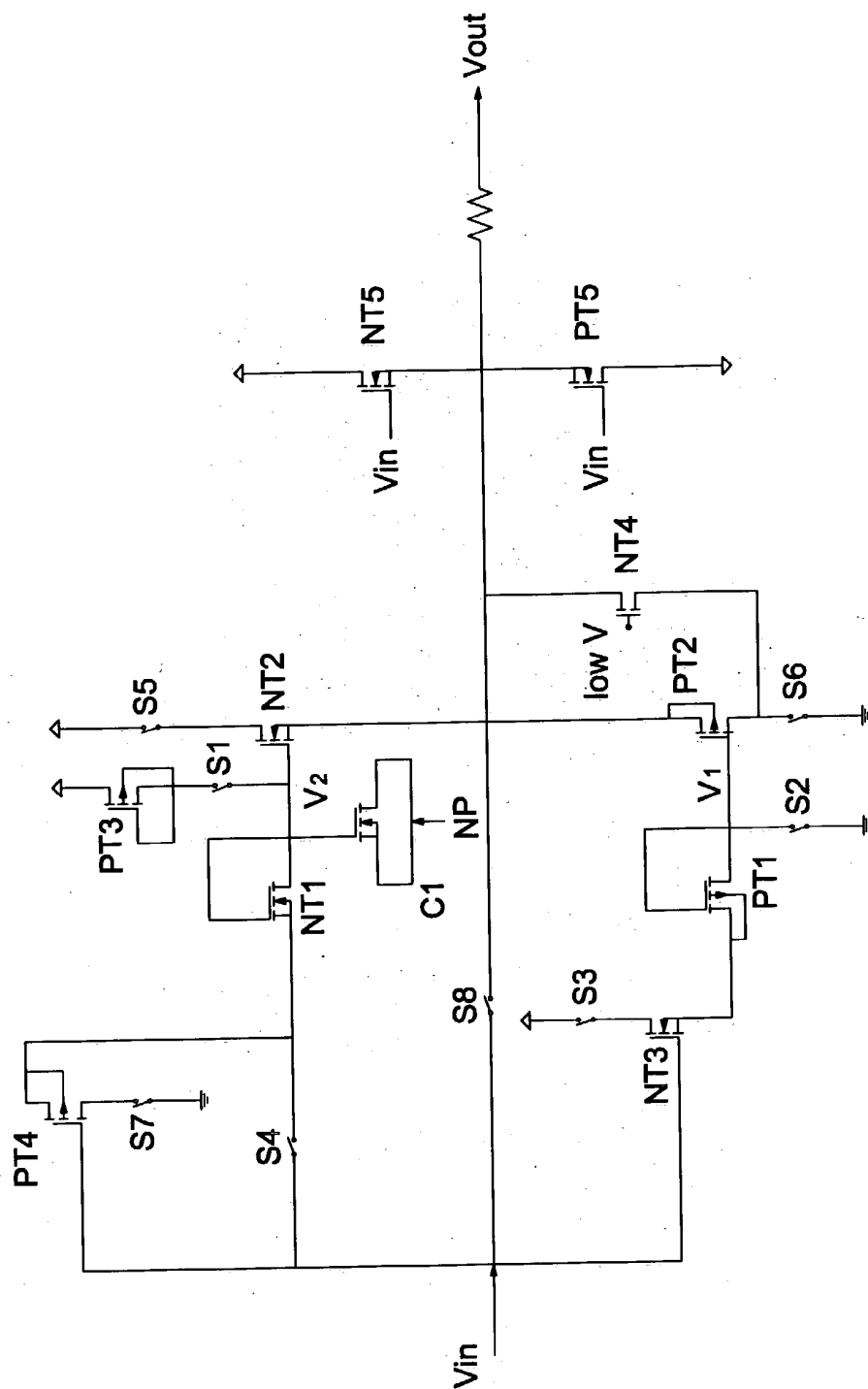
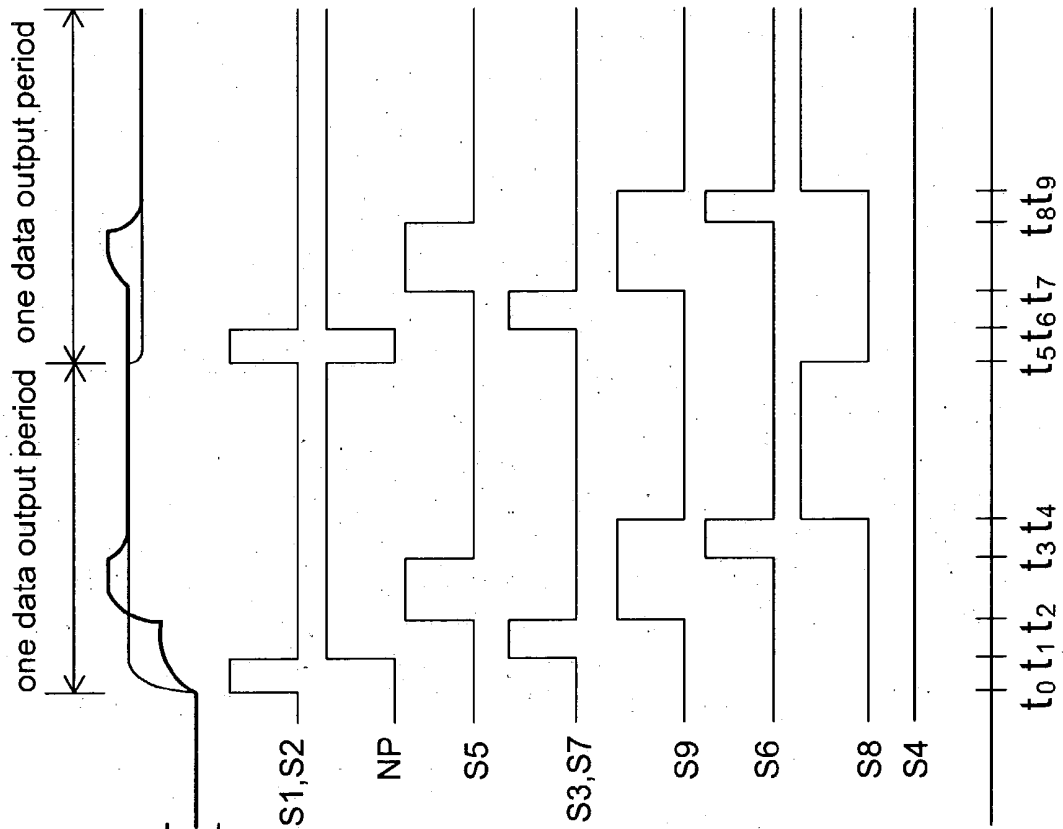
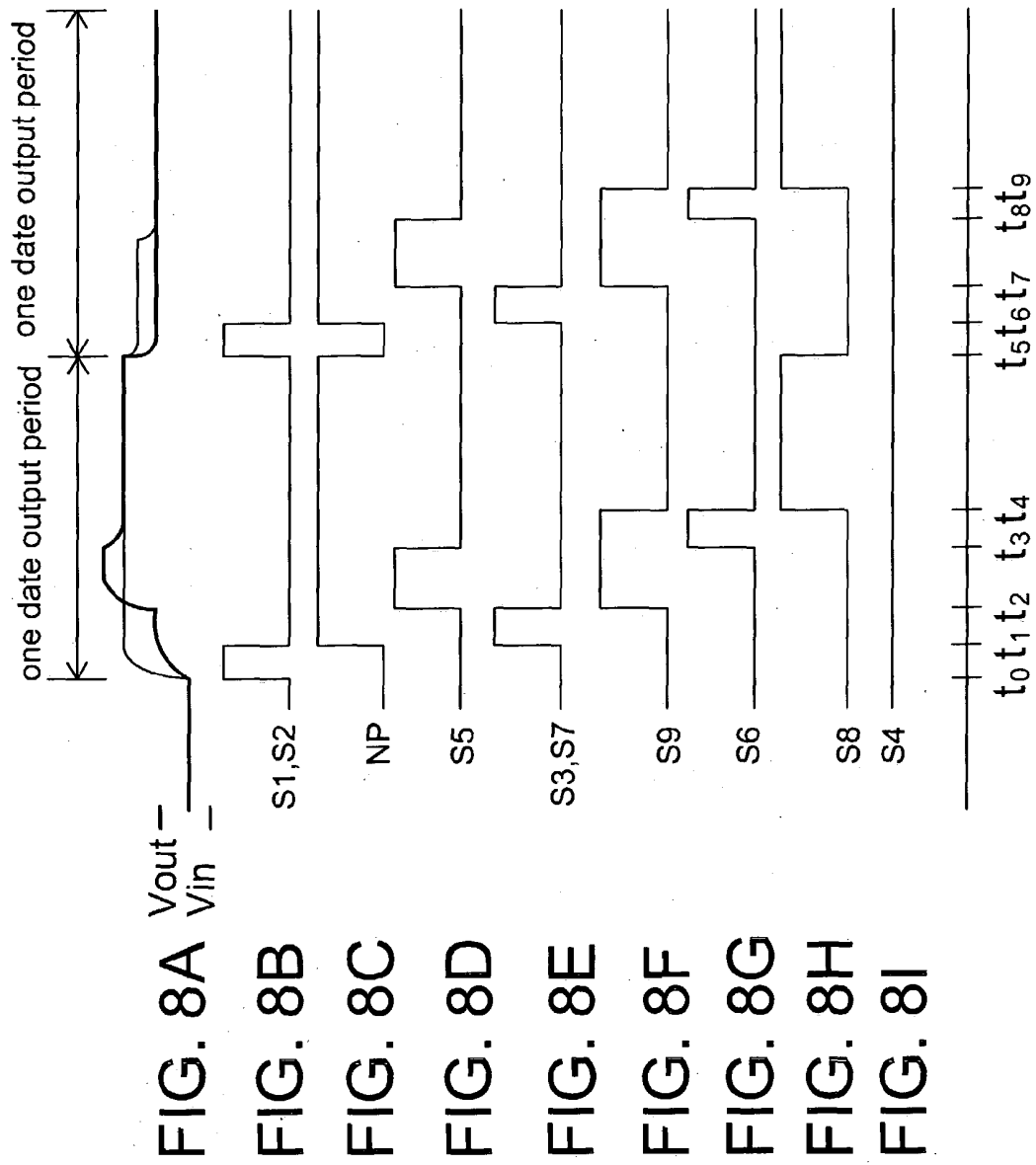


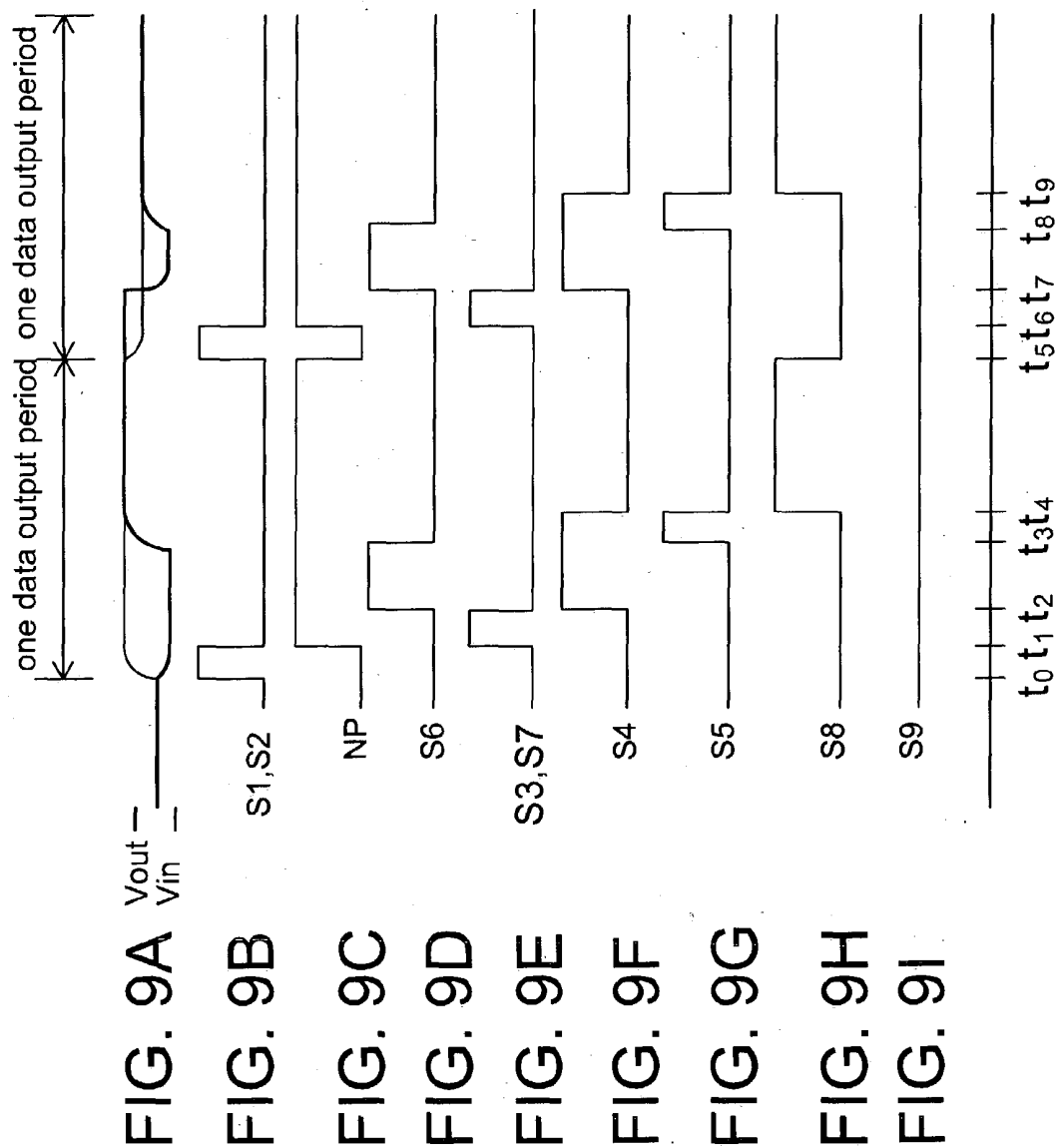
FIG. 4

S1	S2	NP	S3(S7)	S4	S5	S6	S8
ON	ON	Low	OFF	OFF	OFF	OFF	OFF
OFF	OFF	High	ON	OFF	OFF	OFF	OFF
OFF	OFF	High	OFF	ON	OFF	ON	OFF
OFF	OFF	High	OFF	ON	ON	OFF	OFF
OFF	OFF	High	OFF	ON	OFF	OFF	ON

FIG. 5







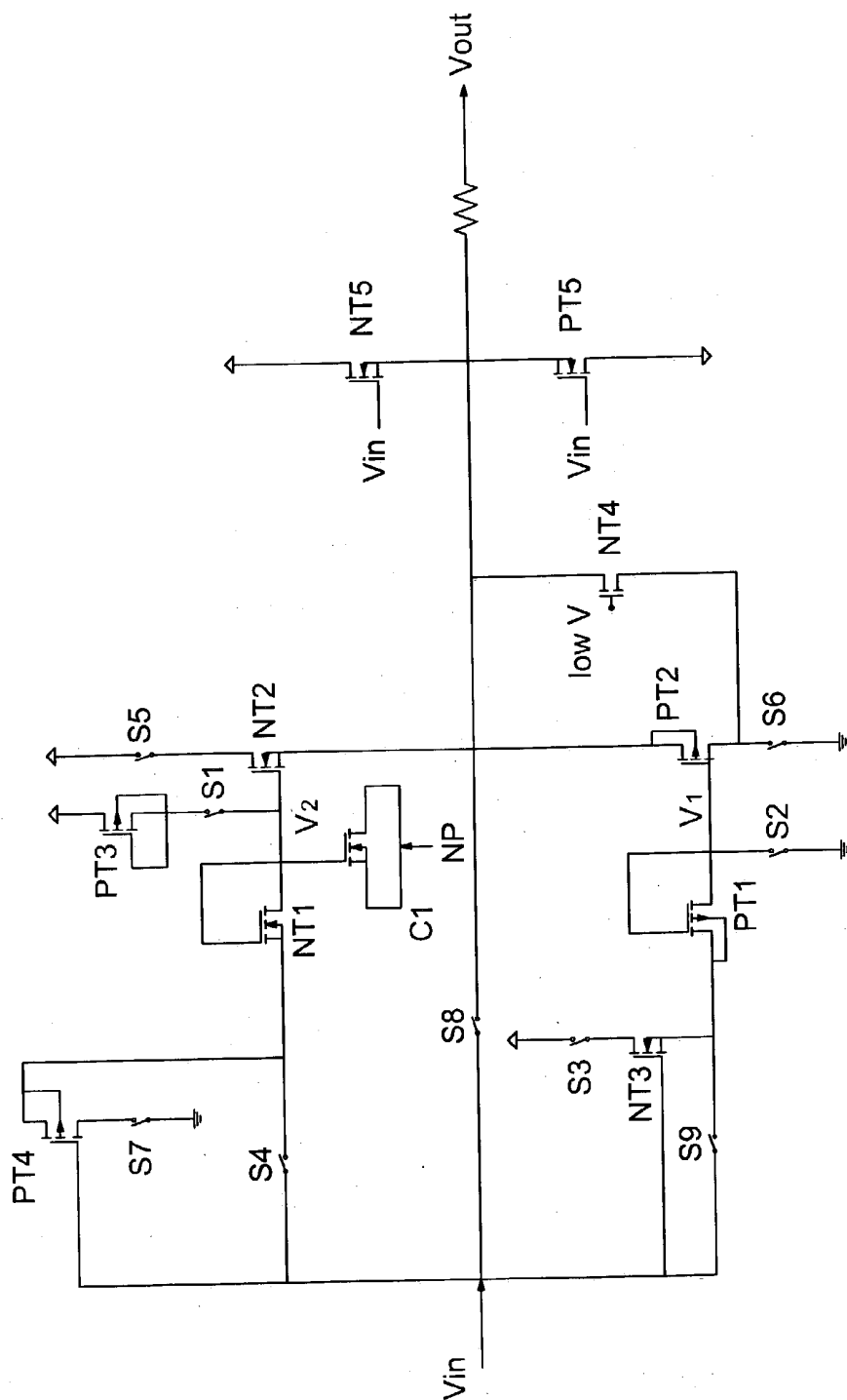


FIG. 10

S1	S2	NP	S3(S7)	S4	S9	S5	S6	S8
ON	ON	Low	OFF	OFF	OFF	OFF	OFF	OFF
OFF	OFF	High	ON	OFF	OFF	OFF	OFF	OFF
OFF	OFF	High	OFF	OFF	ON	ON	OFF	OFF
OFF	OFF	High	OFF	OFF	ON	OFF	ON	OFF
OFF	OFF	High	OFF	OFF	OFF	OFF	OFF	ON

FIG. 11

LOW POWER SOURCE DRIVER FOR LIQUID CRYSTAL DISPLAY

BACKGROUND OF THE INVENTION

[0001] 1. Field of the Invention

[0002] The present invention relates to an apparatus for driving a liquid crystal display (LCD) apparatus, and more particularly, to a low power source driver for use in the LCD driving apparatus.

[0003] 2. Description of the Related Art

[0004] Since LCD panels are thinner in size and lower in power dissipation as compared with cathode-ray tube (CRT) panels, the LCD panels have recently been applied to personal computers, word processors, color telereceivers. Particularly, since active matrix-type LCD apparatuses have a high-speed response, a fine screen with a high quality, and a multi-gradation display, the active matrix-type LCD apparatuses have been in demand.

[0005] Generally, an active matrix-type LCD apparatus is constructed by a semiconductor substrate having thin film metal wire, a transparent pixel electrodes and thin-film transistors (TFTs), a counter substrate having a transparent common electrode, and liquid crystal inserted between the semiconductor substrate and the counter substrate. A gradation voltage is applied to each pixel electrode by controlling the TFT with a switching function, and transmittance of the liquid crystal is changed by the difference in voltage between each pixel electrode and the common electrode to provide display on the screen.

[0006] Provided on the semiconductor substrate are data lines for applying gradation voltages to the pixel electrodes and scan lines for applying switching control signals (scan signals) to the TFTs. Then, when the scan signal of the scan line is at a high level, all the TFTs connecting the scan line are turned ON, and the gradation voltages sent to the data line are applied to the pixel electrodes through the TFTs. When the scan signal becomes low to turn OFF the TFTs, the difference in voltage between each pixel electrode and the common electrode is maintained until the next gradation voltages are applied to the pixel electrodes. Thus, when scan signals are sequentially sent to each scan line, gradation voltages are applied to all the pixel electrodes, so that display on the screen is renewed at every frame period.

[0007] An LCD driving apparatus for driving the data lines is required to charge/discharge a large load of each data line including a liquid crystal capacitance, wiring resistances and wiring capacitance.

[0008] An LCD driving apparatus is generally constructed by a voltage divider, a decoder and driver connected to a data line. Conventionally, the driver is implemented by operational amplifier (see: S. Saito et al., "A 6-bit Digital Data Printer for Color TFT-LCDs", SID 95 Digest, pp. 257-260, 1995). Since the operational amplifier has a high current supplying capability, the driver can drive the data line having a large capacitance load at a high speed. Additionally, even when the threshold voltages of transistors within the operational amplifier fluctuate slightly, the fluctuation of the output voltage of the operational amplifier is relatively small. In addition, the output voltage can be highly accurate.

[0009] In the prior art driver, however, the number of operational amplifiers with a large number of elements increases with the number of data lines. Therefore, if an LCD driving apparatus using the prior art driver is constructed in the form of a single integrated circuit device, the size of the integrated circuit device must be increased to accommodate enough operational amplifiers thereby increasing the manufacturing cost thereof. In addition, steady currents are required for the operational amplifiers, which increases the power dissipation. The structure is not suitable for use of low power loss. The detailed technology for employing the operational amplifier in an LCD driving apparatus can be found in U.S. Pat. No. 6,075,524, issued to Ruta, entitled "Integrated Analog Source Driver For Active Matrix Liquid Crystal Display". U.S. Pat. No. 6,127,997, issued to Tsuchi, entitled "Deriver For Liquid Crystal Display Apparatus With No Operational Amplifier" discloses another LCD driving apparatus which is constructed without the operational amplifier. However, there is still a problem of larger channel precharge charge loss since a large swing of charging or discharging operation is carried out in the structure.

SUMMARY OF THE INVENTION

[0010] It is an object of the present invention to provide a source driver for use in an LCD driving apparatus which is capable of reducing the manufacturing cost and the power dissipation, obtaining accurate source drive output and reducing loading charge loss.

[0011] The present invention provides a source driver for receiving an input voltage and generating an output voltage to drive a data line in a liquid crystal display apparatus. In the source driver of the present invention, first and second P-channel MOS transistors are used to trace the input voltage thereby eliminating the body effect in the n-well process and keeping the loading charge loss constant. The first and second P-channel MOS transistors have a common gate connected to a drain of the first P-channel MOS transistor wherein the second P-channel MOS transistor has a source connected to an output terminal. First and second N-channel MOS transistors have a common gate connected to a drain of the first N-channel MOS transistor, and the second N-channel MOS transistor has a source connected to the output terminal. A third N-channel MOS transistor has a gate connected to an input terminal, a source connected to the source of the first P-channel MOS transistor. A third P-channel MOS transistor has a source connected to the power supply terminal, a gate connected to a drain of the third P-channel MOS transistor. A first switch is connected between the drain of the third P-channel MOS transistor and the drain of the first N-channel MOS transistor. A second switch is connected between the ground terminal and the drain of the first P-channel MOS transistor. A third switch is connected between a power supply terminal and the drain of the third N-channel MOS transistor. A fourth switch is connected between the input terminal and a source of the first N-channel MOS transistor. A fifth switch is connected between the power supply terminal and a drain of the second N-channel MOS transistor. A sixth switch is connected between the ground terminal and a drain of the second P-channel MOS transistor. A first capacitor for receiving a control signal to boost the voltage of the drain of the first N-channel MOS transistor on the level of at least the input voltage plus the threshold voltage of the N-channel MOS

transistor is connected between the ground and the drain of the first N-channel MOS transistor. According to one aspect of the present invention, the source driver further comprises a fourth P-channel MOS transistor and a seventh switch. The fourth P-channel MOS transistor has a gate connected to the input terminal and a source connected to the source of the first N-channel MOS transistor. The seventh switch is connected between the ground terminal and a drain of the fourth P-channel MOS transistor.

[0012] According to one aspect of the present invention, the source driver further comprises a ninth switch connected between the input terminal and a source of the third N-channel MOS transistor.

[0013] According to another aspect of the present invention, the source driver further comprises a fourth N-channel MOS transistor having a gate connected to a low voltage, a source connected to the drain of the second P-channel MOS transistor and a drain connected to the output terminal.

[0014] According to another aspect of the present invention, the source driver further comprises an eighth switch connected between the input terminal and the output terminal. The eighth switch is turned ON after operation of the second P-channel MOS transistor or the second N-channel MOS transistor as a source follower.

[0015] The LCD driving apparatus of the present invention constructed without the operational amplifier can significantly reduce the above problem of larger channel pre-charge loss.

BRIEF DESCRIPTION OF THE DRAWINGS

[0016] Other objects, advantages, and novel features of the invention will become more apparent from the following detailed description when taken in conjunction with the accompanying drawings.

[0017] FIG. 1 is a circuit diagram illustrating a prior art LCD driving apparatus;

[0018] FIG. 2 is a circuit diagram illustrating a first embodiment of the driver according to the present invention;

[0019] FIGS. 3A through 3 are timing diagrams for explaining an operation of the driver of FIG. 2 and FIG. 4;

[0020] FIG. 4 is a circuit diagram of a modification of the driver of FIG. 2;

[0021] FIG. 5 is a table showing the operation of the driver of FIG. 2;

[0022] FIG. 6 is a circuit diagram illustrating a second embodiment of the driver according to the present invention;

[0023] FIGS. 7A through 7 are timing diagrams for explaining a first operation of the driver of FIG. 6;

[0024] FIGS. 8A through 8 are timing diagrams for explaining a second operation of the driver of FIG. 6;

[0025] FIGS. 9A through 9 are timing diagrams for explaining a third operation of the driver of FIG. 6;

[0026] FIG. 10 is a circuit diagram of a modification of the driver of FIG. 6; and

[0027] FIG. 11 is a table showing the operation of the driver of FIG. 6.

DESCRIPTION OF THE PREFERRED EMBODIMENTS

[0028] Before the description of the preferred embodiments according to the present invention, a typical LCD driving apparatus will be explained with reference to FIG. 1. As shown, the LCD driving apparatus is generally constructed by a voltage divider 101, a decoder 102 and a driver 103 connected to a data line DL. The data line DL is also connected via TFTs (not shown) to pixel electrodes. The voltage divider 101 is formed by resistors R1, R2, . . . , R64 for generating multi-gradation voltages. Also, the decoder 102 is formed by CMOS switches provided at intersections between lines connected to the resistors R1, R2, . . . , R64 and lines for receiving video data signals D0, D1, . . . , D5.

[0029] FIG. 2 shows a source driver according to a first embodiment of the present invention. In the source driver of the present invention, first and second P-channel MOS transistors are used to trace the input voltage thereby eliminating the body effect in n-well process and keeping the loading charge loss constant. The first and second P-channel MOS transistors PT1, PT2 have a common gate connected to a drain of the first P-channel MOS transistor PT1, and the second P-channel MOS transistor PT2 has a source connected to an output terminal. First and second N-channel MOS transistors NT1, NT2 have a common gate connected to a drain of the first N-channel MOS transistor NT1, and the second N-channel MOS transistor NT2 has a source connected to the output terminal. A third N-channel MOS transistor NT3 has a gate connected to an input terminal, and a source connected to the source of the first P-channel MOS transistor PT1. A third P-channel MOS transistor PT3 has a drain connected to the power supply terminal, a gate connected to a source of the third P-channel MOS transistor PT3. A first switch S1 is connected between the source of the third P-channel MOS transistor PT3 and the drain of the first N-channel MOS transistor NT1. A second switch S2 is connected between the ground terminal and the drain of the first P-channel MOS transistor PT1. A third switch S3 is connected between a power supply terminal and a drain of the third N-channel MOS transistor NT3. A fourth switch S4 is connected between the input terminal and a source of the first N-channel MOS transistor NT1. A fifth switch S5 is connected between the power supply terminal and a drain of the second N-channel MOS transistor NT2. A sixth switch S6 is connected between the ground terminal and a drain of the second P-channel MOS transistor PT2. A first capacitor C1 for receiving a control signal NP to boost the voltage of the drain of the first N-channel MOS transistor on the level of at least the input voltage plus the threshold voltage of the N-channel MOS transistor is connected between the control signal terminal and the drain of the first N-channel MOS transistor. A capacitor of any type (e.g., Metal-Insulator-Metal form or Air-gap form) can be used as the first capacitor C1.

[0030] The third N-channel MOS transistor NT3, the third and second switches S3, S2 are operated to bias a voltage at the gate of the second P-channel MOS transistor PT2 to a voltage shifted from the input voltage by a threshold voltage of the first P-channel MOS transistor PT1 plus a threshold voltage of the third N-channel MOS transistor NT3. The third P-channel MOS transistor PT3, and the fourth and first switches S4, S1 are operated to bias a voltage at the gate of the second N-channel MOS transistor NT2 to a voltage

shifted from the input voltage by a threshold voltage of the first N-channel MOS transistor NT1. The sixth switch S6 is operated to operate the second P-channel MOS transistor PT2 as a source follower, so that a voltage shifted from a voltage at the common gate of the first and second P-channel MOS transistors PT1, PT2 by a threshold voltage of the second P-channel MOS transistor PT2 is output as the output voltage at the output terminal. The fifth switch S5 is operated to operate the second N-channel MOS transistor NT2 as a source follower, so that a voltage shifted from a voltage at the common gate of the first and second N-channel MOS transistors NT1, NT2 by a threshold voltage of the second N-channel MOS transistor NT2 is output as the output voltage at the output terminal.

[0031] In the source driver of the present invention, the source driver may further comprise a fourth P-channel MOS transistor PT4 and a seventh switch S7. The fourth P-channel MOS transistor PT4 has a gate connected to the input terminal and a source connected to the source of the first N-channel MOS transistor NT1. The seventh switch S7 is connected between the ground terminal and a drain of the fourth P-channel MOS transistor PT4. Furthermore, the source driver of the present invention may further comprise a fourth N-channel MOS transistor NT4 has a gate connected to a low voltage, a source connected to the drain of the second P-channel MOS transistor and a drain connected to the output terminal.

[0032] An operation of the driver of FIG. 2 is explained next with reference to FIGS. 3A, 3B, 3C, 3D, 3E, 3F, 3G and 3H which show a two-data output period.

[0033] First, at time t0, as shown in FIG. 3B, the switches S1 and S2 are both turned ON. A bias voltage V1 at the gates of the transistors PT1 and PT2 is 0 volt. Also, a bias voltage V2 at the gates of the transistors NT1 and NT2 is V_{DD} V_{thp4} volt.

[0034] Next, at time t1, as shown in FIGS. 3B and 3C, the switches S1 and S2 are turned OFF and the control signal NP is at ON state to boost the voltage of the drain of the first N-channel MOS transistor NT1 to a voltage higher than any predefined gamma voltage plus a threshold voltage of the N-channel MOS transistor. At the same time, the switch S3, S7 and the transistor PT4 (if PT4 and S7 exist) are turned ON, thus the bias voltage V1 and V2 become

$$V_1 = V_{in} - V_{thn3} + V_{thp1}$$

$$V_2 = V_1 + V_{th1} + V_{thp4}$$

[0035] where V_{thp1} is a threshold voltage of the transistor PT1, V_{th3} is a threshold voltage of the transistor NT3, V_{thn1} is a threshold voltage of the transistor NT1 and V_{thp4} is a threshold voltage of the transistor PT4

[0036] Next, at time t2, as shown in FIG. 3D, 3E, the switch S4 and S6 is turned ON, thus the bias voltage V2 becomes

$$V_2 = V_{in} + V_{thp1}$$

[0037] In this state, since the transistor PT2 serves as a source follower, the output voltage V_{out} becomes

$$V_{out} = V_{in} - V_{thn3} + V_{thp1} - V_{thp2}$$

[0038] where V_{thp2} is a threshold voltage of the transistor PT2.

[0039] Note that, the fourth P-channel MOS transistor PT4 and the seventh switch S7 are not an essential aspect of the present invention. If the fourth P-channel MOS transistor PT4 and the seventh switch S7 do not exist, the operation at time t1 and t2 will become a little different as followed. At the time t1, as shown in FIGS. 3C and 3F, the switch S3 is turned ON, thus the bias voltage V1 becomes

$$V_1 = V_{in} - V_{thn3} + V_{thp1}$$

[0040] Next, at time t2, as shown in FIG. 3D, 3E, the switch S4 and S6 is turned ON, thus the bias voltage V2 becomes

$$V_2 = V_{in} + V_{thn1}$$

[0041] In this state, since the transistor PT2 serves as a source follower, the output voltage V_{out} becomes

$$V_{out} = V_{in} - V_{thn3} + V_{thp1} - V_{thp2}$$

[0042] where V_{thp2} is a threshold voltage of the transistor PT2.

[0043] The bias voltage V2 is the same at time t2 with or without the fourth P-channel MOS transistor PT4 and the seventh switch S7. However, there has large current at the input terminal if the source driver of the present invention have not the fourth P-channel MOS transistor PT4 and the seventh switch S7. Therefore, if V_{thp1} is similar to (≈) V_{thp2}, the output voltage V_{out} is replaced by

$$V_{out} \approx V_{in} - V_{th3}$$

[0044] Note that, if the transistors PT1 and PT2 are formed closely to each other and their sizes are approximately the same as each other, the threshold voltages V_{thp1} can be approximately the same as the threshold voltage V_{thp2}.

[0045] Next, at time t3, as shown in FIG. 3G, the switch S5 is turned ON. In this state, since the transistor NT2 serves as a source follower, the output voltage V_{out} becomes

$$V_{out} = V_{in} + V_{thn1} - V_{thn2}$$

[0046] where V_{thn2} is a threshold voltage of the transistor NT2. Therefore, if V_{thn1} is similar to (≈) V_{thn2}, the output voltage V_{out} is replaced by

$$V_{out} \approx V_{in}$$

[0047] Thus, in the first embodiment, the output voltage V_{out} can be equal to the input voltage V_{in}, and a high accuracy voltage buffer by the transistor PT2 as a source follower combined with the transistor NT2.

[0048] Also note that, in the general N-well process, since the source follower of P-channel MOS transistor cannot trace the ultra-low Gamma voltage, it's better to put one more N-channel MOS transistor to pull to ground when the video data selects the ultra-low gamma voltage. The fourth N-channel MOS transistor NT4 is used to pull the output voltage to ground when the input voltage is smaller than the threshold voltage of the transistor PT2.

[0049] The operation of time t5 through time t8 are repeated the operation of time t0 through time t3.

[0050] FIG. 4 shows a circuit diagram of a modification of the driver of FIG. 2. The source driver further comprises a eighth switch S8 connected between the input terminal and the output terminal. The eighth switch S8 is turned ON after operation of the second P-channel MOS transistor PT2 or the second N-channel MOS transistor NT2 as a source

follower, as shown in **FIG. 3H**. Due to the poor driving capability of the source follower when V_{out} is approaching V_{in} , the use of the eighth switch **S8** can reach the accurate optimum value (target value). Another reason of using the switch **S8** is to compensate for the difference between the output voltage V_{out} and its optimum value due to the difference in threshold voltage between the transistors **NT1** and **NT2**. For example, the operation of the driver of **FIG. 4** is as shown in **FIG. 3A through 3H**. During a time period, from time t_2 to time t_4 , the output voltage V_{out} is represented by

$$V_{out} = V_{in} + V_{thn1} - V_{thn2}$$

[0051] In this case, if there is a difference between V_{thn1} and V_{thn2} , the output voltage V_{out} deviates by ΔV from its optimum value, i.e., V_{in} . Next, at time t_4 , the switches **S5** and **S6** are both turned OFF and the switch **S8** is turned ON, respectively, so that the output voltage V_{out} will be averaged by source outputs with the same gray output voltage and will eventually become equal to the input voltage V_{in} since ΔV is small if the time is long enough. Even the **S8** period is not long, each source output with the same gray output can still be averaged, and the ΔV from its optimum value can be offset cancelled by opposite polarity since the source output in the opposite polarity would be at the same order offset from its optimum value. Thus, in **FIG. 4**, by turning on **S8**, the accuracy of the output voltage V_{out} is enhanced. The source driver further comprises fifth N-channel MOS transistor **NT5** and fifth P-channel MOS transistor **PT5**, the fifth N-channel MOS transistor **NT5** having a source connected to the output terminal, a drain connected to the power supply terminal, a gate connected to the input terminal, the fifth P-channel MOS transistor **PT5** having a source connected to the output terminal, a drain connected to the ground terminal, a gate connected to the input terminal. The fifth N-channel MOS transistor **NT5** and fifth P-channel MOS transistor **PT5** are used for charging and discharging source output for the first step to approach the target value. With the aid of the fifth N-channel MOS transistor **NT5** and fifth P-channel MOS transistor **PT5**, the source output can be operated more accurate.

[0052] **FIG. 5** is a table showing the operation of the driver of **FIG. 2**. The operation of the driver as shown in **FIG. 5** can be arranged easily by the logic circuit (not shown in **FIG. 2**).

[0053] **FIG. 6** shows a source driver according to a second embodiment of the present invention. The structure of **FIG. 6** is substantially identical to the structure of the **FIG. 2**. The main differences therebetween are set forth below. The fourth P-channel MOS transistor **PT4** and the seventh switch **S7** are necessary in the second embodiment of the source driver of the present invention. Furthermore, an eighth switch **S8** is connected between the input terminal and the source of the first P-channel MOS transistor **PT1**.

[0054] Since the source follower of P-channel MOS transistor cannot trace the low Gamma voltage, there still needs the source follower of N-channel MOS transistor to trace the low Gamma voltage. For example, the **V0** expresses the highest Gamma voltage, the **V63** expresses the lowest Gamma voltage. The Gamma voltages of **V1**, **V2**, . . . **V62** are decreased in sequence. The second embodiment of the driver according to the present invention separates the Gamma voltage into three parts. The Gamma voltages of

part I are between **V0** and **V7**. The Gamma voltages of part II are between **V8** and **V55**. The Gamma voltages of part III are between **V56** and **V63**.

[0055] **FIGS. 7A through 7F** show timing diagrams for explaining first operation of the driver of **FIG. 6** in part I, which show a two-data output period. The switch **S4** is always turned OFF in the part I and part II.

[0056] First, at time t_0 , as shown in **FIG. 7B**, the switches **S1** and **S2** are both turned ON. A bias voltage V_1 at the gates of the transistors **PT1** and **PT2** is 0 volt. Also, a bias voltage V_2 at the gates of the transistors **NT1** and **NT2** is $V_{DD} - V_{thp3}$ volt.

[0057] Next, at time t_1 , as shown in **FIGS. 7B, 7C** and **7E**, the switches **S1** and **S2** are turned OFF and the switch **S3** and **S7** are turned on. In addition, the control signal **NP** is at ON state to boost the voltage of the drain of the first N-channel MOS transistor **NT1** on the level of the input voltage plus the threshold voltage of the N-channel MOS transistor **NT1** and the threshold voltage of P-channel MOS transistor **PT4**. At the time, the bias voltage V_2 becomes

$$V_2 = V_{in} + V_{thn1} - V_{thp4}$$

[0058] Next, at time t_2 , as shown in **FIG. 7F**, the switches **S3** and **S7** are turned OFF and the switch **S9** is turned on thus the bias voltage V_1 becomes

$$V_1 = V_{in} + V_{thp1}$$

[0059] In the meanwhile the switch **S5** is turned ON. In this state, since the transistor **NT2** serves as a source follower, the output voltage V_{out} becomes

$$V_{out} = V_{in} + V_{thn1} + V_{thp4} - V_{thn2}$$

[0060] Therefore, if V_{thn1} is similar to ($\approx$) V_{thn2} , the output voltage V_{out} is replaced by

$$V_{out} = V_{in} + V_{thp4}$$

[0061] Note that the maximum possible voltage level of ($V_{in} + V_{thp4}$) is power supply voltage.

[0062] Next, at time t_3 , as shown in **FIGS. 7D** and **7G**, the switch **S5** is turned OFF and the switch **S6** is turned ON. In this state, since the transistor **PT2** serves as a source follower, the output voltage V_{out} becomes

$$V_{out} = V_{in} + V_{thp1} - V_{thp2}$$

[0063] where V_{thp2} is a threshold voltage of the transistor **PT2**. Therefore, if V_{thp1} is similar to ($\approx$) V_{thp2} , the output voltage V_{out} is replaced by

$$V_{out} \approx V_{in}$$

[0064] Note that, if the transistors **PT1** and **PT2** are formed closely to each other and their sizes are approximately the same as each other, the threshold voltages V_{thp1} can be approximately the same as the threshold voltage V_{thp2} . Also note that, since in the general N-well process, the source follower of P-channel MOS transistor can not trace the ultra-low Gamma voltage, it's better to put one more N-channel MOS transistor to pull to ground when the video data selects to the ultra-low gamma voltage. The fourth N-channel MOS transistor **NT4** is used to pull the output voltage to ground when the input voltage V_{in} is smaller than the threshold voltage of the transistor **PT2**. The operation of time t_5 through time t_8 are repeated the operation of time t_1 through time t_3 .

[0065] FIGS. 8A through 8F are timing diagrams for explaining a second operation of the driver of FIG. 6 in part II. The operations of the driver in part II is similar to the operations of the driver in part I except that the relation ($V_{in}+V_{thp4}$) during S5 turning on can be maintained, as shown in the FIGS. 7A and 8A.

[0066] FIGS. 9A through 9F are timing diagrams for explaining a third operation of the driver of FIG. 6 in part III. Since the Gamma voltages of part III between V56 and V63 are lower, the source follower of P-channel MOS transistor can not trace the low Gamma voltage exactly, the source follower of N-channel MOS transistor is used mainly to trace the low Gamma voltage. The switch S9 is always turned OFF in the part III.

[0067] First, at time t0, as shown in FIG. 9B, the switches S1 and S2 are both turned ON. A bias voltage V1 at the gates of the transistors PT1 and PT2 is 0 volt. Also, a bias voltage V2 at the gates of the transistors NT1 and NT2 is $V_{DD}-V_{thp3}$ volt.

[0068] Next, at time t1, as shown in FIGS. 9B and 9C, the switches S1 and S2 are turned OFF and the switches S3 and S7 are turned on. In addition, the control signal NP is at ON state to boost the voltage of the drain of the first N-channel MOS transistor NT1 on the level of the input voltage plus the threshold voltage of the N-channel MOS transistor NT1 and the threshold voltage of the P-channel MOS transistor PT4.

[0069] Next, at time t2, as shown in FIGS. 9D and 9F, the switch S4 is turned ON and the bias voltage V1 and V2 become

$$V_1 = V_{in} + V_{thp1} - V_{thn3}$$

$$V_2 = V_{in} + V_{thn1}$$

[0070] At the same time, the switch S6 is turned ON. In this state, since the transistor PT2 serves as a source follower, the output voltage V_{out} becomes

$$V_{out} = V_{in} + V_{thp1} - V_{thn3} - V_{thp2}$$

[0071] where V_{thp2} is a threshold voltage of the transistor PT2. Therefore, if V_{thp1} is similar to ($\approx$) V_{thp2} , the output voltage V_{out} is replaced by

$$V_{out} \approx V_{in} + V_{thn1} - V_{thn3}$$

[0072] Note that, if the transistors PT1 and PT2 are formed closely to each other and their sizes are approximately the same as each other, the threshold voltages V_{thp1} can be approximately the same as the threshold voltage V_{thp2} .

[0073] Next, at time t3, as shown in FIG. 9G, the switch S5 is turned ON. In this state, since the transistor NT2 serves as a source follower, the output voltage V_{out} becomes

$$V_{out} = V_{in} + V_{thn1} - V_{thn2}$$

[0074] where V_{thn2} is a threshold voltage of the transistor NT2. Therefore, if V_{thn1} is similar to ($\approx$) V_{thn2} , the output voltage V_{out} is replaced by

$$V_{out} \approx V_{in}$$

[0075] FIG. 10 shows a circuit diagram of modification of the drivers of FIG. 6. The source driver further comprises a eighth switch S8 connected between the input terminal and the output terminal. The eighth switch S8 is turned ON after operation of the second P-channel MOS transistor PT2 or the second N-channel MOS transistor NT2 as a source

follower, as shown in FIGS. 7H, 8H and 9H. Due to the poor driving capability of the source follower when V_{out} is approaching V_{in} , the use of switch S8 can reach the accurate optimum value (target value). Another reason of using the switch S8 is described in FIG. 4. The source driver further comprises a fifth N-channel MOS transistor NT5 and a fifth P-channel MOS transistor PT5. The fifth N-channel MOS transistor NT5 has a source connected to the output terminal, a drain connected to the power supply terminal, a gate connected to the input terminal. The fifth P-channel MOS transistor PT5 has a source connected to the output terminal, a drain connected to the ground terminal, a gate connected to the input terminal. The fifth N-channel MOS transistor and fifth P-channel MOS transistor are also used for more accurate output voltage.

[0076] FIG. 11 is a table showing the operation of the driver of FIG. 6. Although the operation of the driver is different from part I, II to part III, the operation of the driver as shown in FIG. 7-9 can still be arranged easily by the logic circuit. (not shown in Fig.) Namely, the switch between S5 and S6, or S4 and S8 in part I, II, III can be easily implemented by the multiplexer.

[0077] Thus, in the second embodiment, the output voltage V_{out} can be equal to the input voltage V_{in} , and a high current supply capability by the transistor PT2 as a source follower combined with the transistor NT2 as a source follower can be exhibited.

[0078] In the above-mentioned embodiments, the P-channel MOS transistors can be other P-channel transistors of a gate insulation type, and the N-channel MOS transistors can be other N-channel transistors of a gate insulation type.

[0079] As explained hereinabove, according to the present invention, since the driver has no operational amplifier with a large number of elements and the novel driver circuit design according to the present invention applied to the LCD can adequately use the wafer IC process, the chip size of the driver can be reduced thereby lowering not only the manufacturing cost but also the power dissipation.

[0080] Although the invention has been explained in relation to its preferred embodiment, it is to be understood that many other possible modifications and variations can be made without departing from the spirit and scope of the invention as hereinafter claimed.

What is claimed is:

1. A source driver in a liquid crystal display apparatus for receiving an input voltage and generating an output voltage to drive a data line, comprising:

a ground terminal to which a ground voltage is applied;

a power supply terminal to which a power supply voltage higher than the ground voltage is applied;

an input terminal for receiving the input voltage;

an output terminal for generating the output voltage;

first and second P-channel MOS transistors each having a gate connected to a drain of the first P-channel MOS transistor, the second P-channel MOS transistor having a source connected to the output terminal;

first and second N-channel MOS transistors each having a gate connected to a drain of the first N-channel MOS

transistor, the second N-channel MOS transistor having a source connected to the output terminal;

a third N-channel MOS transistor having a gate connected to the input terminal and a source connected to a source of the first P-channel MOS transistor;

a third P-channel MOS transistors having a drain connected to the power supply terminal, and a gate connected to a source of the third P-channel MOS transistor;

a first switch connected between the source of the third P-channel MOS transistor and the drain of the first N-channel MOS transistor;

a second switch connected between the ground terminal and the drain of the first P-channel MOS transistor;

a third switch connected between the power supply terminal and a drain of the third N-channel MOS transistor;

a fourth switch connected between the input terminal and a source of the first N-channel MOS transistor;

a fifth switch connected between the power supply terminal and a drain of the second N-channel MOS transistor;

a sixth switch connected between the ground terminal and a drain of the second-P-channel MOS transistor; and

a first capacitor connected between a control signal terminal and the drain of the first N-channel MOS transistor.

2. The source driver as claimed in claim 1, wherein the first capacitor is operated to boost the voltage of the drain of the first N-channel MOS transistor on the level of at least the input voltage plus the threshold voltage of the N-channel MOS transistor at a predetermined time.

3. The source driver as claimed in claim 1, wherein the third and second switches are operated to bias the gate of the second P-channel MOS transistor a voltage of $(V_{in} + V_{thp1} - V_{thn3})$ at a predetermined time, V_{in} being the input voltage, V_{thp1} being a threshold voltage of the first P-channel MOS transistor, V_{thn3} being a threshold voltage of the third N-channel MOS transistor.

4. The source driver as claimed in claim 1, wherein the fourth and first switches are operated to bias the gate of the second N-channel MOS transistor a voltage of $(V_{in} + V_{thn1})$ at a predetermined time, V_{in} being the input voltage, V_{thn1} being a threshold voltage of the first N-channel MOS transistor.

5. The source driver as claimed in claim 1, wherein the sixth switch is operated to operate the second P-channel MOS transistor as a source follower.

6. The source driver as claimed in claim 1, wherein the fifth switch is operated to operate the second N-channel MOS transistor as a source follower.

7. The source driver as claimed in claim 1, further comprising a fourth N-channel MOS transistor having a source connected to the drain of the second P-channel MOS transistor and a drain connected to the output terminal, wherein the fourth N-channel MOS transistor is used to substantially pull the output voltage to ground at predetermined time when the input voltage is smaller than the threshold voltage of the transistor.

8. The source driver as claimed in claim 1, further comprising:

a fourth P-channel MOS transistor having a gate connected to the input terminal and a source connected to the source of the first N-channel MOS transistor; and

a seventh switch connected between the ground terminal and a drain of the fourth P-channel MOS transistor.

9. The source driver as Claimed in claim 8, further comprising a ninth switch connected between the input terminal and a source of the third N-channel MOS transistor.

10. The source driver as claimed in claim 9, wherein while the fourth and ninth switches are kept turned OFF and ON respectively, and then the fifth and sixth switches are turned ON and OFF respectively, to operate the second N-channel MOS transistor as a source follower.

11. The source driver as claimed in claim 10, wherein after the fifth and sixth switches are turned ON and OFF respectively for a predetermined period, and then the fifth and sixth switches are turned OFF and ON respectively, to operate the second P-channel MOS transistor as a source follower.

12. The source driver as claimed in claim 9, wherein while the fourth and ninth switches are kept turned ON and OFF respectively, and then the fifth and sixth switches are turned OFF and ON respectively, to operate the second P-channel MOS transistor as a source follower.

13. The source driver as claimed in claim 12, wherein after the fifth and sixth switches are turned OFF and ON respectively for a predetermined period, and then the fifth and sixth switches are turned ON and OFF respectively, to operate the second N-channel MOS transistor as a source follower.

14. The source driver as claimed in claim 9, further comprising a eighth switch connected between the input terminal and the output terminal, the eighth switch being turned ON after operation of the second P-channel MOS transistor or the second N-channel MOS transistor as a source follower.

15. The source driver as claimed in claim 9, further comprising a fourth N-channel MOS transistor having a source connected to the drain of the second P-channel MOS transistor and a drain connected to the output terminal, wherein the fourth N-channel MOS transistor is used to substantially pull the output voltage to ground at predetermined time when the input voltage is smaller than the threshold voltage of the transistor.

16. The source driver as claimed in claim 9, further comprising a fifth N-channel MOS transistor and a fifth P-channel MOS transistor, wherein the fifth N-channel MOS transistor has a source connected to the output terminal, a drain connected to the power supply terminal, and a gate connected to the input terminal, and the fifth P-channel MOS transistor has a source connected to the output terminal, a drain connected to the ground terminal, and a gate connected to the input terminal.

17. The source driver as claimed in claim 1, wherein, after the gate of the second P-channel MOS transistor is biased on the voltage level of $(V_{in} - V_{thn3} + V_{thp1})$, the sixth and fifth switches are turned ON and OFF, respectively, to operate the second P-channel MOS transistor as a source follower V_{in}

being the input voltage, V_{thp1} being a threshold voltage of the first P-channel MOS transistor, V_{thn3} being a threshold voltage of the third N-channel MOS transistor.

18. The source driver as claimed in claim 1, wherein, after the gate of the second N-channel MOS transistor is biased on the voltage level of $(V_{in} + V_{thn1})$, the sixth and fifth switches are turned OFF and ON, respectively, to operate the second N-channel MOS transistor as a source follower, V_{in} being the input voltage, V_{thn1} being a threshold voltage of the first N-channel MOS transistor.

19. The source driver as claimed in claim 1, further comprising a eighth switch connected between the input terminal and the output terminal, the eighth switch being

turned ON after operation of the second P-channel MOS transistor or the second N-channel MOS transistor as a source follower.

20. The source driver as claimed in claim 1, further comprising a fifth N-channel MOS transistor and a fifth P-channel MOS transistor, wherein the fifth N-channel MOS transistor has a source connected to the output terminal, a drain connected to the power supply terminal, and a gate connected to the input terminal, and the fifth P-channel MOS transistor has a source connected to the output terminal, a drain connected to the ground terminal, and a gate connected to the input terminal.

* * * * *

专利名称(译)	用于液晶显示器的低功率源驱动器		
公开(公告)号	US20040263464A1	公开(公告)日	2004-12-30
申请号	US10/602587	申请日	2003-06-25
[标]申请(专利权)人(译)	邱铭承		
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其他公开文献	US7050033		
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摘要(译)

公开了一种用于接收输入电压并产生输出电压以驱动液晶显示装置中的数据线的源极驱动器。在源极驱动器中，第一和第二P沟道MOS晶体管一起用作主要源极跟随器以跟踪输入电压，从而消除体效应并保持负载电荷损失恒定。使用第一和第二N沟道MOS晶体管作为辅助源极跟随器。电容器用于在至少输入电压加上N沟道MOS晶体管的阈值电压的电平上提升第一N沟道MOS晶体管的漏极电压。此外，当输出电压接近输入电压时，额外的开关用于达到精确的输出电压。

